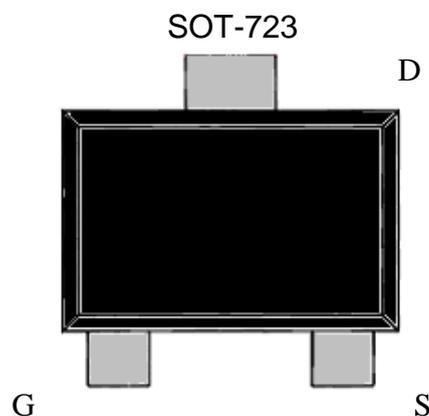


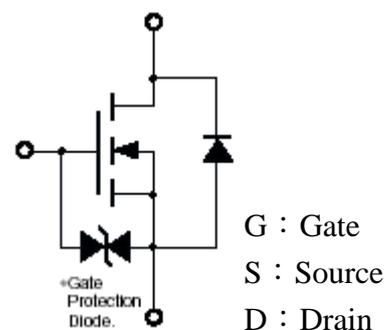
## 20V N-CHANNEL Enhancement Mode MOSFET

### Features:

- Simple drive requirement
- Small package outline
- ESD protected gate
- Pb-free lead plating and halogen-free package



$BV_{DSS}$	20V
$I_D$	560mA
$R_{DS(on)}@V_{GS}=4V, I_D=300mA$	290m $\Omega$ (typ)
$R_{DS(on)}@V_{GS}=2.5V, I_D=300mA$	440m $\Omega$ (typ)
$R_{DS(on)}@V_{GS}=1.8V, I_D=300mA$	845m $\Omega$ (typ)



### Ordering Information

Device	Package	Shipping
KW1702	SOT-723 (Pb-free lead plating and halogen-free package)	8000 pcs / tape & reel

### Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit	
Drain-Source Voltage	V <sub>DS</sub>	20	V	
Gate-Source Voltage	V <sub>GS</sub>	±8		
Continuous Drain Current @ T <sub>A</sub> =25°C, V <sub>GS</sub> =4.5V (Note 3)	I <sub>D</sub>	560	mA	
Continuous Drain Current @ T <sub>A</sub> =85°C, V <sub>GS</sub> =4.5V (Note 3)		400		
Pulsed Drain Current (Notes 1, 2)	I <sub>DM</sub>	2.5	A	
Maximum Power Dissipation (Note 3)	P <sub>D</sub>	T <sub>A</sub> =25°C	150	mW
		T <sub>A</sub> =85°C	80	
ESD susceptibility		2000 (Note 4)	V	
Operating Junction and Storage Temperature	T <sub>j</sub> , T <sub>stg</sub>	-55~+150	°C	

- Note : 1. Pulse width limited by maximum junction temperature.  
 2. Pulse width ≤ 300μs, duty cycle ≤ 2%.  
 3. Surface mounted on FR-4 board.  
 3. Human body model, 1.5kΩ in series with 100pF

### Thermal Performance

Parameter	Symbol	Limit	Unit
Thermal Resistance, Junction-to-Ambient(PCB mounted)	R <sub>th,ja</sub>	833	°C/W

### Electrical Characteristics (Tj=25°C, unless otherwise noted)

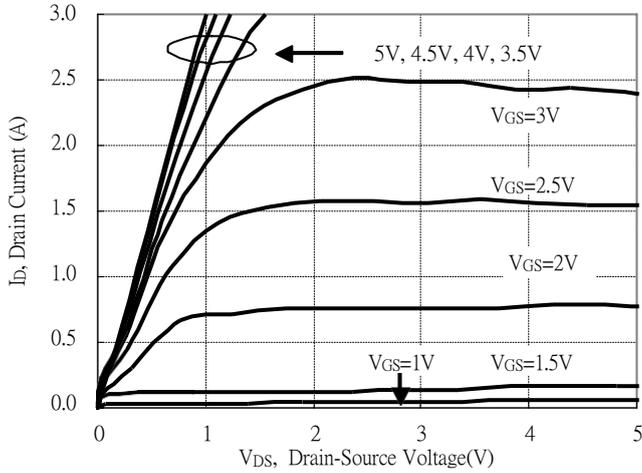
Symbol	Min.	Typ.	Max.	Unit	Test Conditions
<b>Static</b>					
BV <sub>DSS</sub>	20	-	-	V	V <sub>GS</sub> =0, I <sub>D</sub> =250μA
ΔBV <sub>DSS</sub> /ΔT <sub>j</sub>	-	0.02	-	V/°C	Reference to 25°C, I <sub>D</sub> =1mA
V <sub>GS(th)</sub>	0.5	0.92	1.2	V	V <sub>DS</sub> =10V, I <sub>D</sub> =1mA
I <sub>GSS</sub>	-	-	±10	μA	V <sub>GS</sub> =±8V, V <sub>DS</sub> =0
I <sub>DSS</sub>	-	-	1		V <sub>DS</sub> =20V, V <sub>GS</sub> =0
	-	-	10		V <sub>DS</sub> =16V, V <sub>GS</sub> =0 (T <sub>j</sub> =70°C)
*R <sub>DS(ON)</sub>	-	290	400	mΩ	V <sub>GS</sub> =4V, I <sub>D</sub> =300mA
	-	440	600		V <sub>GS</sub> =2.5V, I <sub>D</sub> =300mA
	-	845	1200		V <sub>GS</sub> =1.8V, I <sub>D</sub> =300mA
*G <sub>FS</sub>	-	0.9	-	S	V <sub>DS</sub> =10V, I <sub>D</sub> =300mA
<b>Dynamic</b>					
C <sub>iss</sub>	-	60	-	pF	V <sub>DS</sub> =10V, V <sub>GS</sub> =0, f=1MHz
C <sub>oss</sub>	-	14	-		
C <sub>rss</sub>	-	9	-		

$t_{d(ON)}$	-	5	-	ns	$V_{DS}=10V, I_D=150mA, V_{GS}=4V, R_G=10\Omega$
$t_r$	-	5	-		
$t_{d(OFF)}$	-	24	-		
$t_f$	-	18	-		
$Q_g$	-	0.76	-	nC	$V_{DS}=10V, I_D=250mA, V_{GS}=4.5V$
$Q_{gs}$	-	0.074	-		
$Q_{gd}$	-	0.27	-		
<b>Source-Drain Diode</b>					
$*V_{SD}$	-	0.75	1.2	V	$V_{GS}=0V, I_S=100mA$

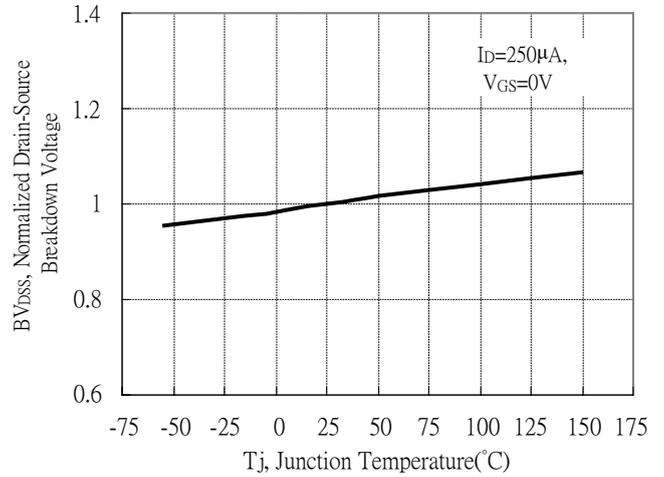
\*Pulse Test : Pulse Width  $\leq 300\mu s$ , Duty Cycle  $\leq 2\%$

## Typical Characteristics

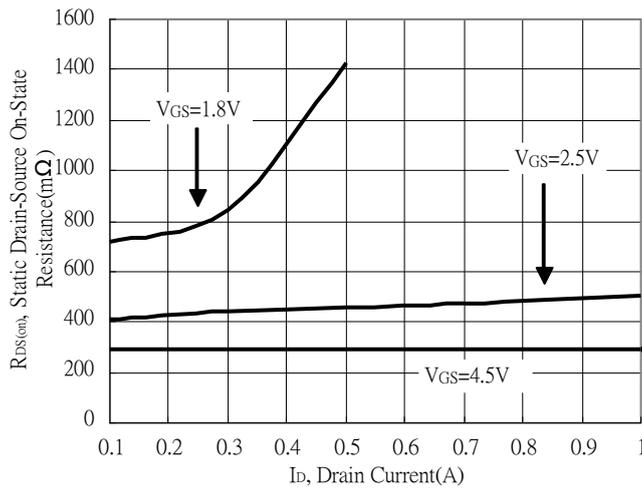
Typical Output Characteristics



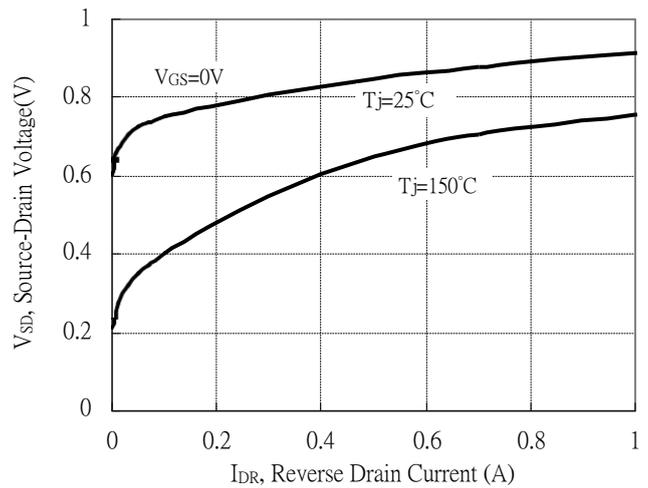
Breakdown Voltage vs Ambient Temperature



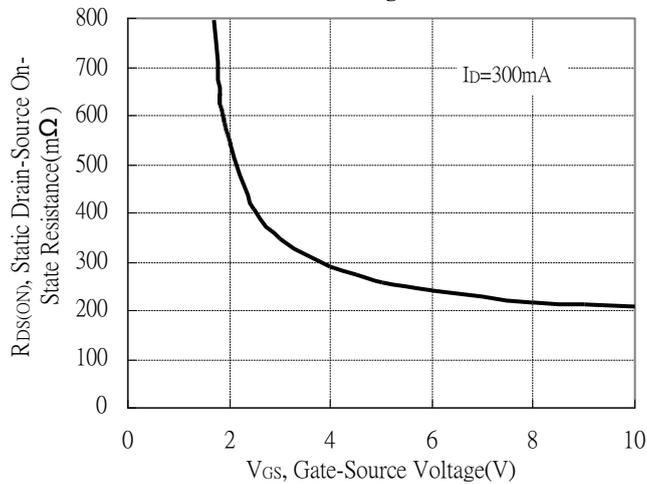
Static Drain-Source On-State resistance vs Drain Current



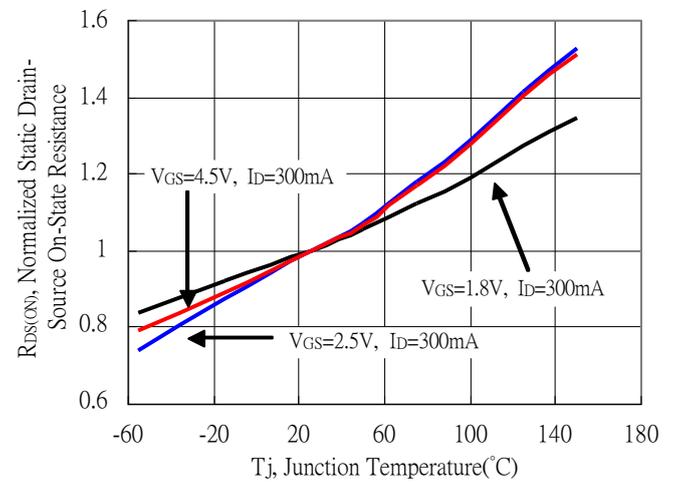
Reverse Drain Current vs Source-Drain Voltage



Static Drain-Source On-State Resistance vs Gate-Source Voltage

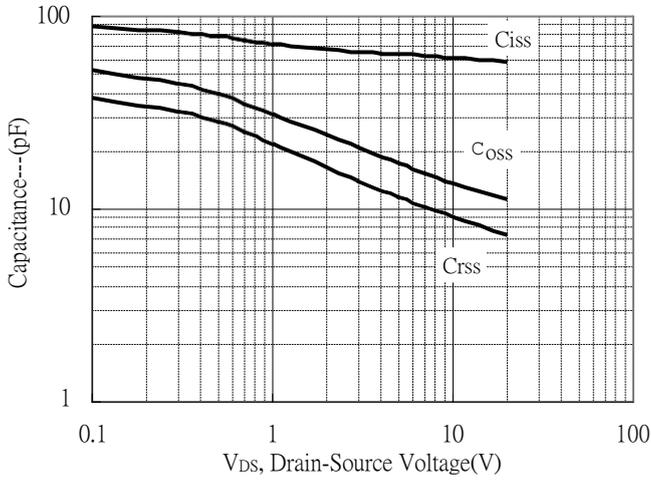


Drain-Source On-State Resistance vs Junction Temperature

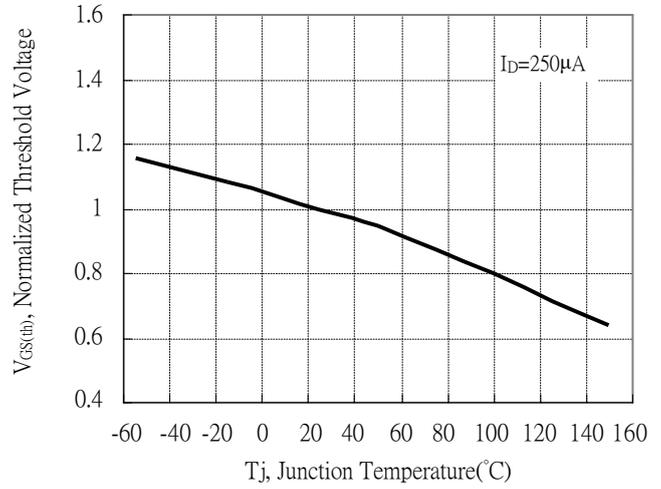


**Typical Characteristics(Cont.)**

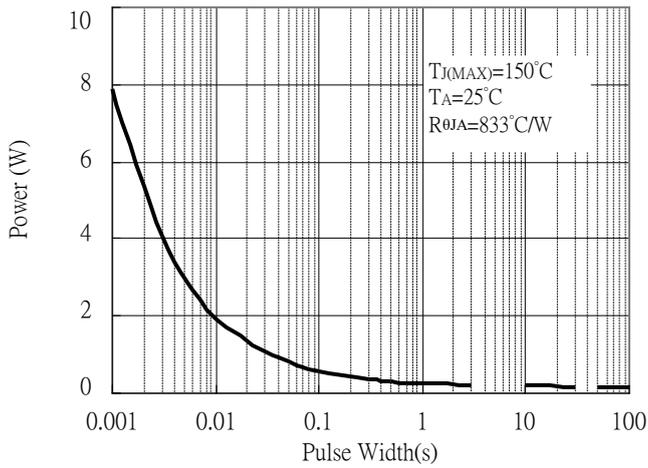
Capacitance vs Drain-to-Source Voltage



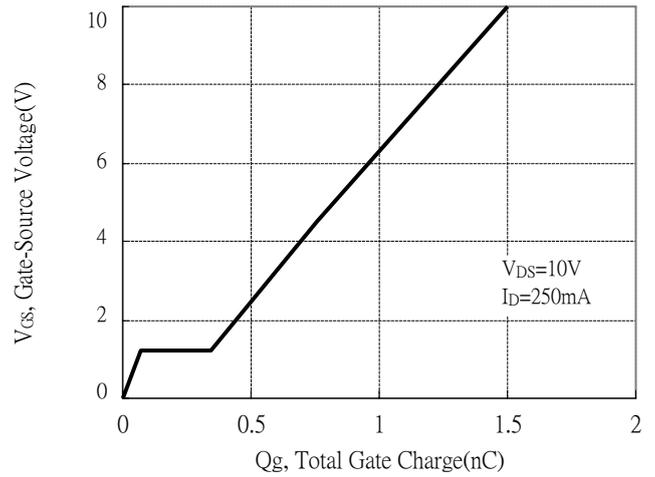
Threshold Voltage vs Junction Temperature



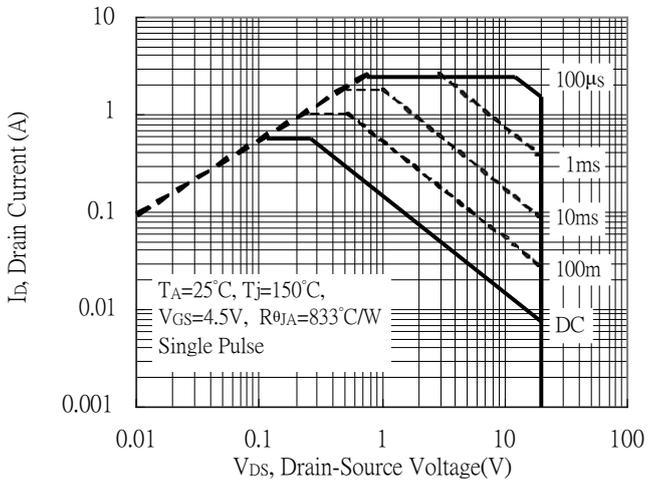
Single Pulse Power Rating, Junction to Ambient  
(Note on page 2)



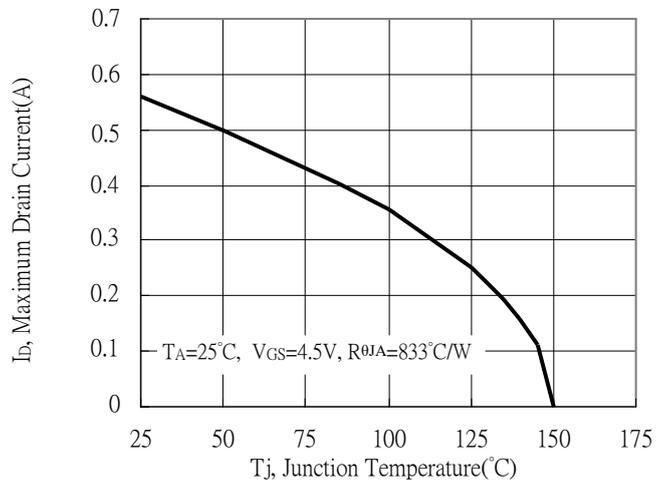
Gate Charge Characteristics



Maximum Safe Operating Area

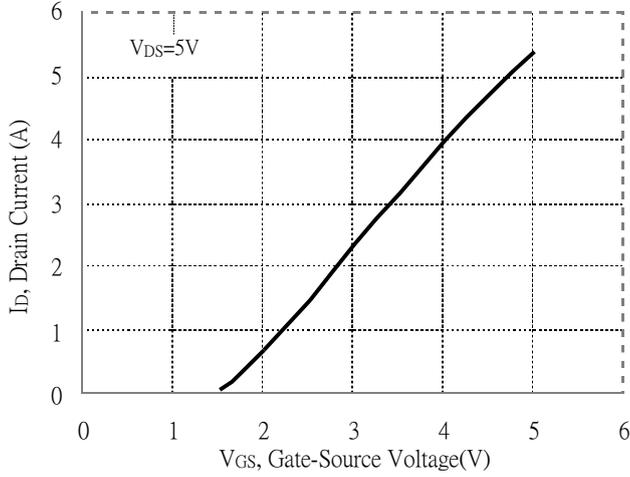


Maximum Drain Current vs Junction Temperature

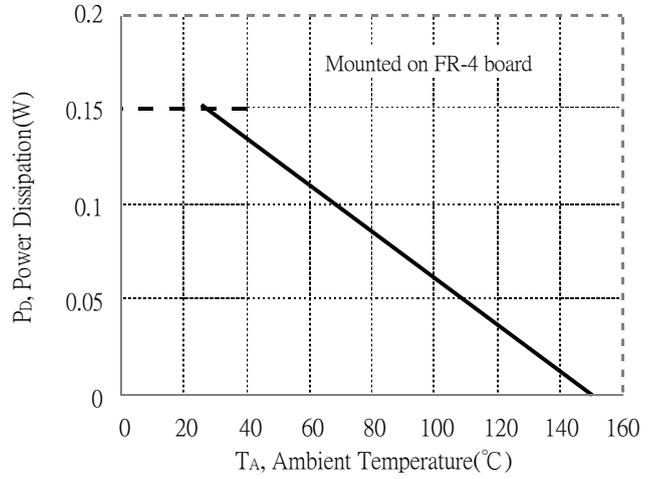


**Typical Characteristics(Cont.)**

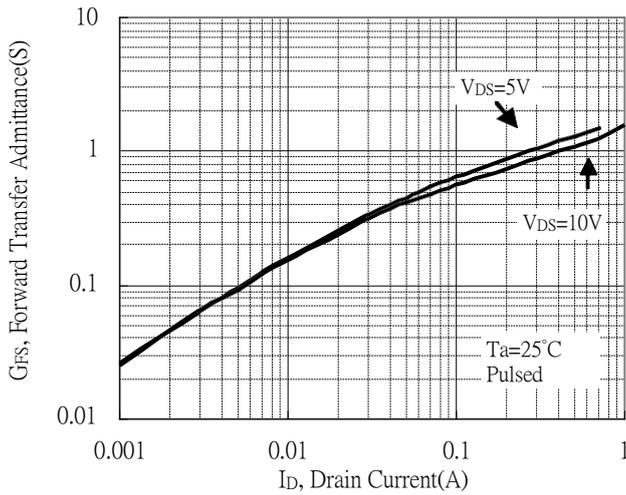
Typical Transfer Characteristics



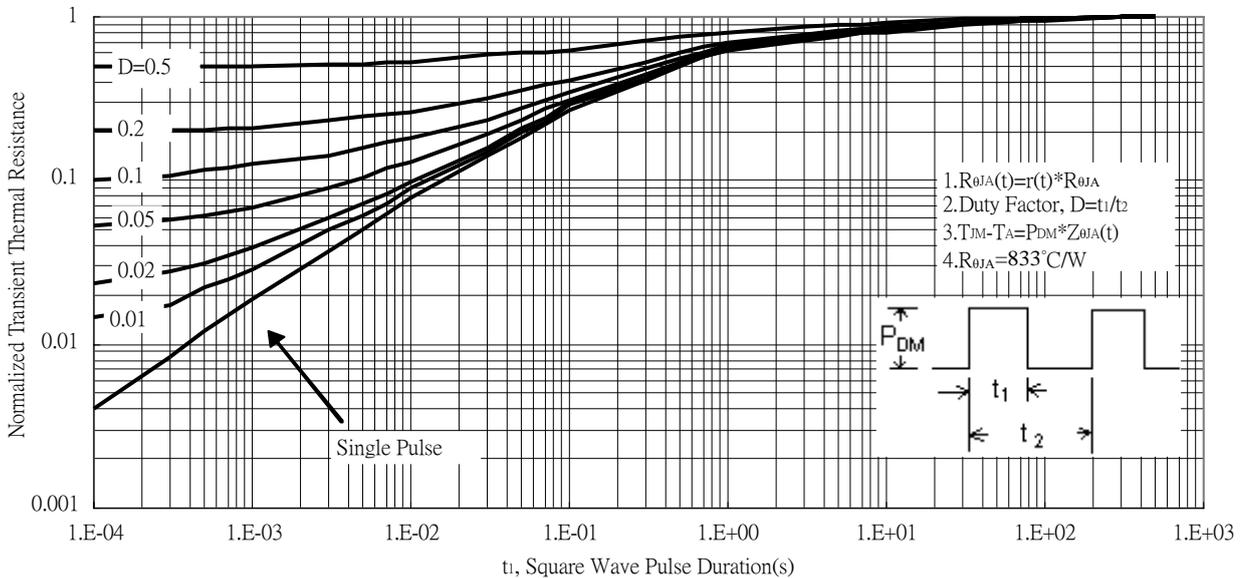
Power Derating Curve



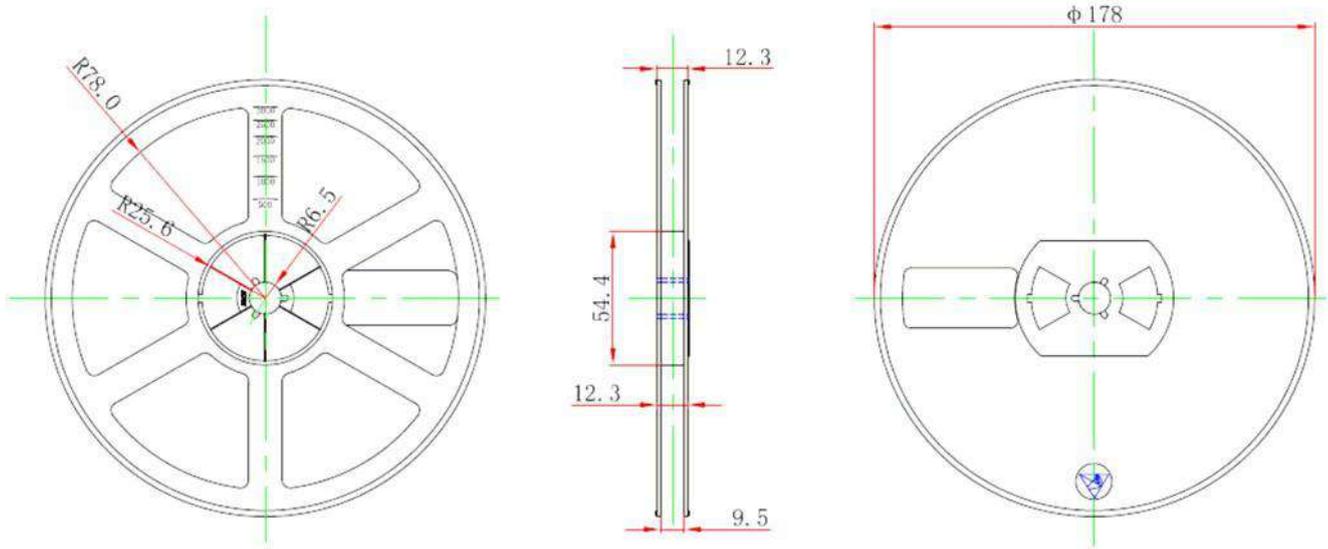
Forward Transfer Admittance vs Drain Current



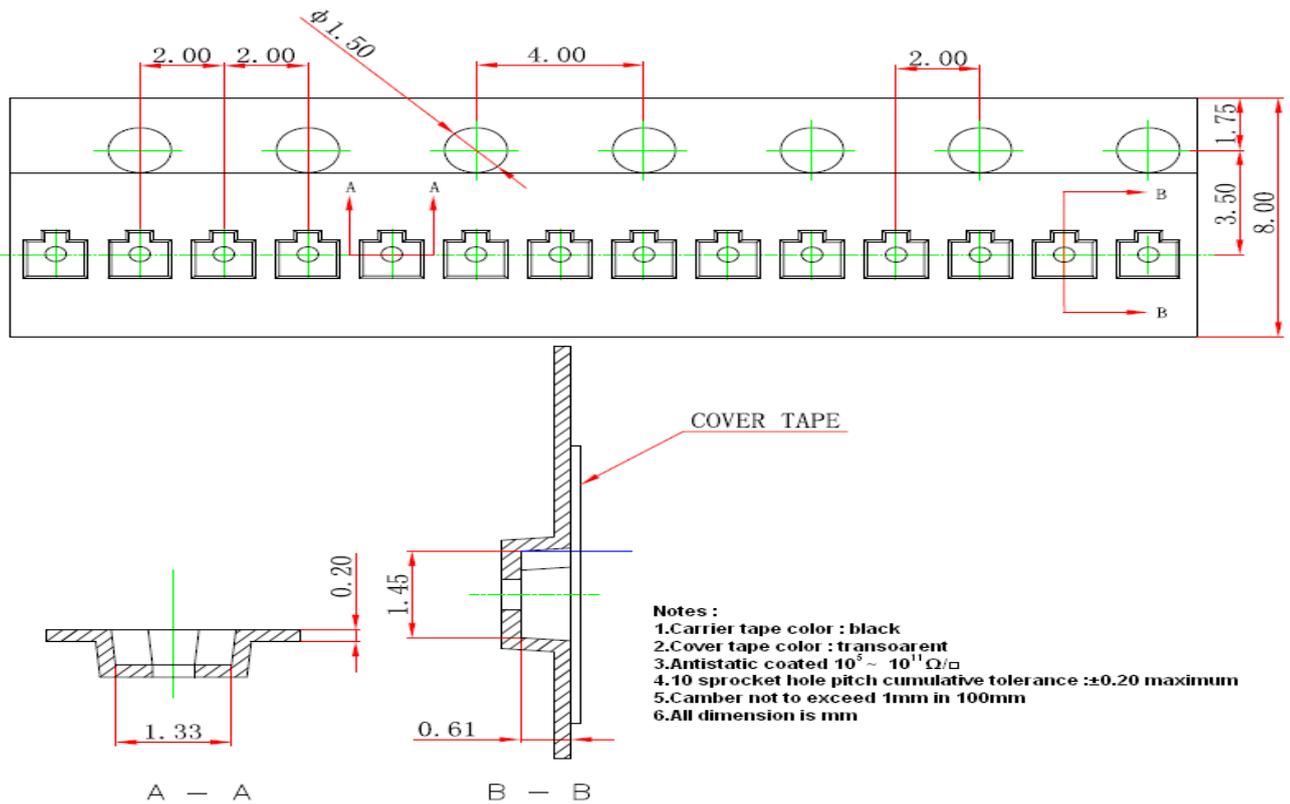
Transient Thermal Response Curves



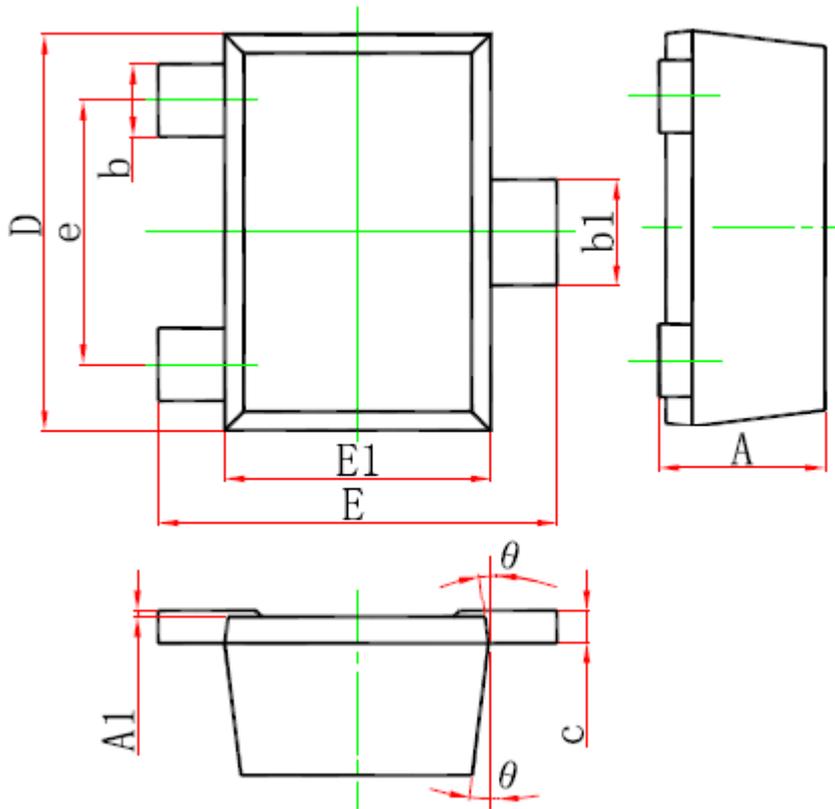
**Reel Dimension**



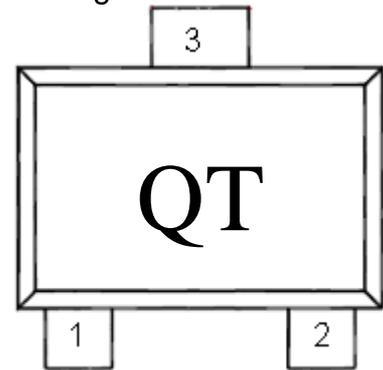
**Carrier Tape Dimension**



**SOT-723 Dimension**



Marking:



3-Lead SOT-723 Plastic  
 Surface Mounted Package  
 Package Code: Y3

Style: Pin 1.Gate 2.Source 3.Drain

\*Typical

DIM	Millimeters		Inches		DIM	Millimeters		Inches	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
A	0.000	0.500	0.000	0.020	D	1.150	1.250	0.045	0.049
A1	0.000	0.050	0.000	0.002	E	1.150	1.250	0.045	0.049
b	0.170	0.270	0.007	0.011	E1	0.750	0.850	0.030	0.033
b1	0.270	0.370	0.011	0.015	e	0.800*		0.031*	
c	0.000	0.150	0.000	0.006	θ	7° REF		7° REF	